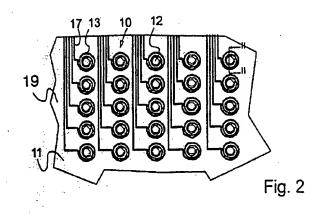
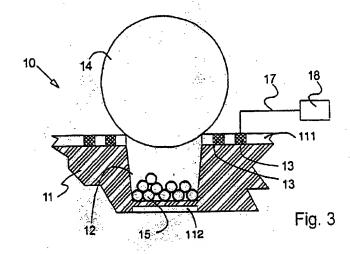
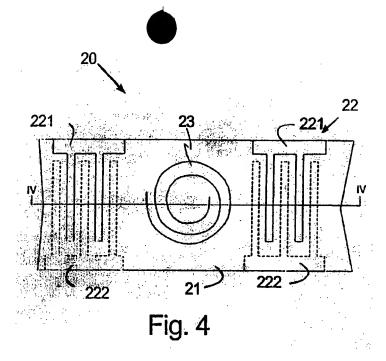


Fig. 1







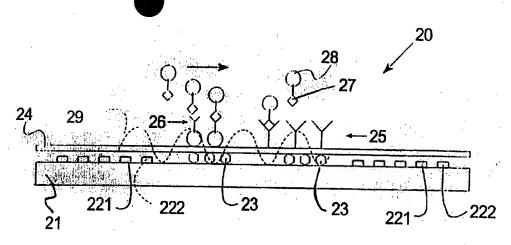
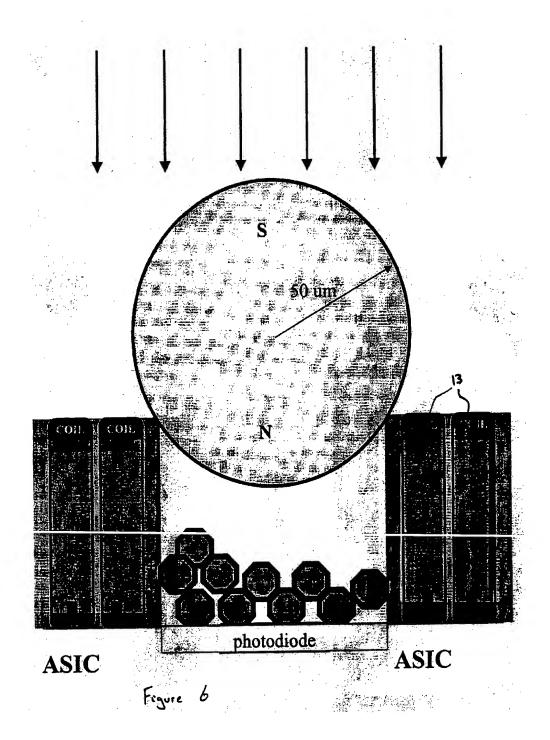
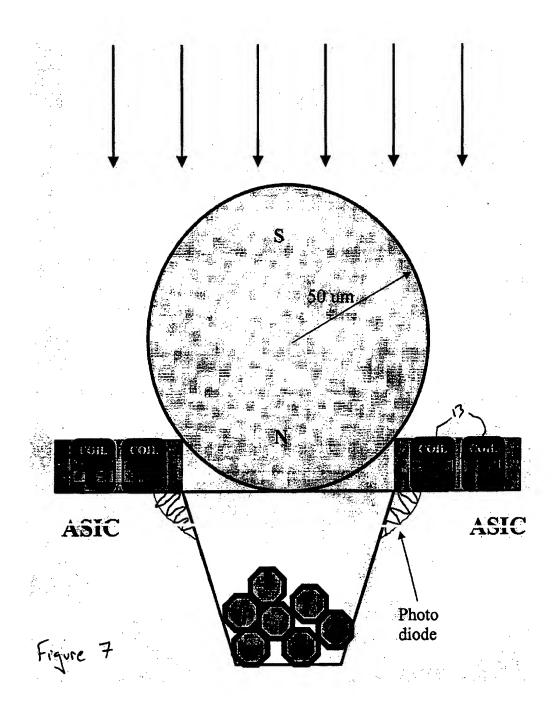
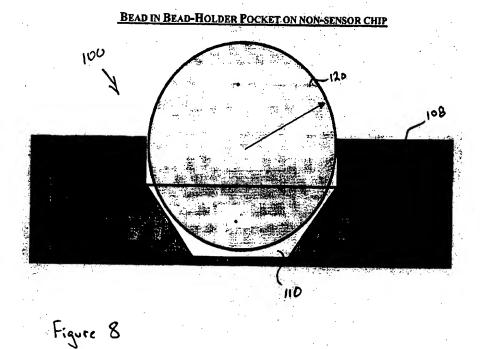


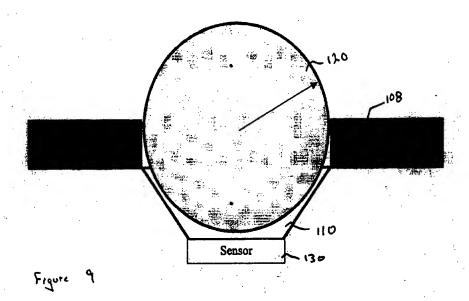
Fig. 5



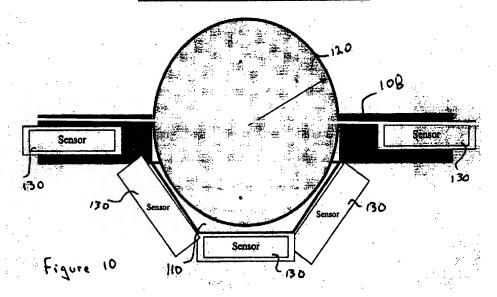




Particle in pocket, in place over sensor



A few examples of some other sensor locations



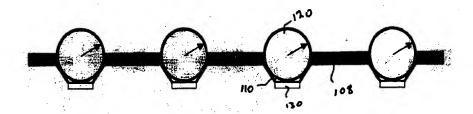
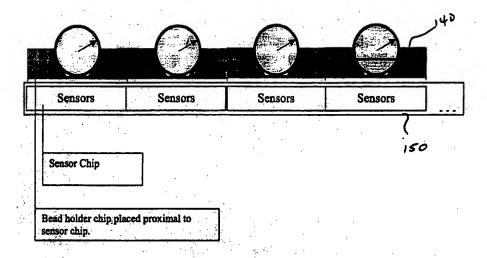


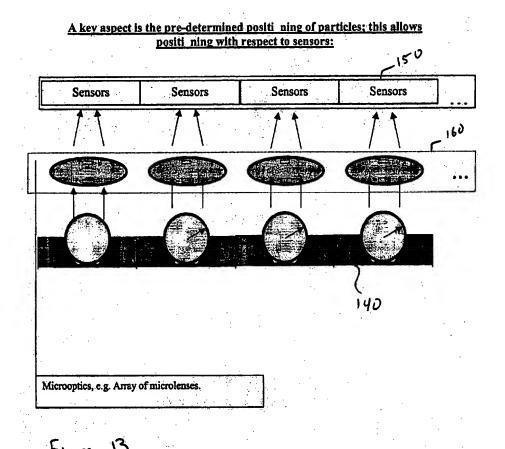
Figure 11

SEPARATELY MANUFACTURED/HANDLEABLE POCKET CHIP AND SENSOR CHIP



Example Sensors: a commercially availble CMOS photodiode array

Figure 12



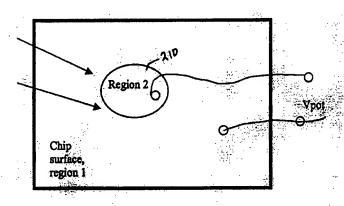


Figure 14. Top view of a silicon surface with a doped region (region 2).
The electric circuit is completed by Ppot using two leads contacting each region.

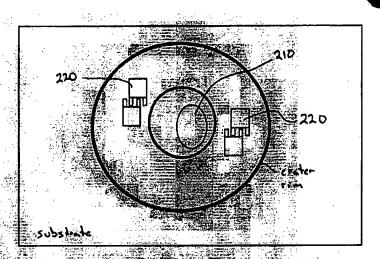


Figure 15. A crater from above, with allowed region (e.g., photodiade) on the bottom and also two circuits with capacitive detection capability on the sloping insides of the capacitive capacitive.

